## TECHSEM's Overseas Representative

As the exclusive overseas marketing partner of TECHSEM, R&D Electronics International Co., Limited takes over all the marketing and sales activities for the world market.



For more information please visit R&D webshop:

WWW.RD-eBUSINESS.COM

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# Power the Future China-based Supplier for the Whole Product Series

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TECH SEMICONDUCTORS CO.,LTD.

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## Profile

1966, founded factory, produced diode & transistor.

1974, successfully produced the first thyristor in China.

1980, established new plant for special IC and high power transistors.

1988, research and develop power semiconductor modules.

2003, complete the privatization reform.

2008, founded a joint-venture company.

2010, IPO at Shenzhen Stock Exchange, stock code: 3000

Tech Semiconductors Co., Ltd. (TECHSEM), is a specialized manufacturer in developing, producing and selling power semiconductor devices. It is unique enterprise listed on stock exchange for power semiconductor in China.

With more than 40 years experience of semiconductor devices manufacturing, TECHSEM has two clean buildings of over 8000M², in which 1000 M² of 100 class clean room. Over 620 staffs work in the company, of which 136 are specialized engineers (6 engineering masters, 32 senior engineers,). TECHSEM offers great advantages in technology and production capability.

TECHSEM has a perfect and effective market net covering throughout China with nearly 200 distributors and 60 sole agents. The production capacity for power semiconductor device up to two million pieces per year.

TECHSEM is pushing on the target of to be the leading competitive supplier for power semiconductors, sincerely hopes to establish trustful and honest business relationship with friends to get mutually benefit and reach a bright future.







## China-based Supplier for the Whole Product Series



## Wafers

Size: 1.5 – 6 inches Voltage: 400 – 7200V

Wafers: phase control thyristror, fast turn-off thyristor, rectifier diode, fast recovery diode



















# Chips

Size: 1.5 – 5 inches Current: 25 –8000A Voltage: 400 – 7200V

Chips: phase control thyristror, fast turn-off thyristor, rectifier diode, fast recovery diode





















# Capsule Device (Thyristors / Diodes)

|                          |            | Phase Control Thyristors   | Code Designation                                     |                               |   |                         |  |           |  |
|--------------------------|------------|--|--|-------------------------------|---|-------------------------|--|-----------|--|
| Key<br>Parameters        | Range      | Features   | Typical Applications                                 |                               |   |                         |  |           |  |
| Current                  | 320-6400A  | Amplifying gates     International standard cases                                | 1.High power industrial and power transmission       |                               |   |                         |  |           |  |
| Voltage                  | 200-7200V  | 3.Hermetic metal cases with ceramic insulators                                   | 3.Controlled rectifiers                              | 1 Soft startors for industion | 3.Controlled rectifiers   | 3.Controlled rectifiers | 3.Controlled rectifiers                                  | Y 50 KK E |  |
| Surge<br>current         | 8-72KA     | Capsule packages for double<br>sided cooling                                     | motors<br>5.AC controllers                           | i T T T                       | rating code   |                         |  |           |  |
| Fast Turn-Off Thyristors |            |  |  | Chip type                     | KP:Phase Control Thyristors   |                         |  |           |  |
| Key<br>Parameters        | Range      | Features   | Typical Applications                                 | Chip diameter (mm)            | KA:High Frequency Thyristors  KS:BI-directional Control Thyristors  ZP:Rectifier Diodes |                         |  |           |  |
| Current                  | 490-4890A  | 1.Interdigitated amplifying gates  | 1.Inductive heating<br>2.Electronic welders          | code for capsule devices      |   |                         |  |           |  |
| Voltage                  | 800-5000V  | 2.Fast turn-on and high di/dt<br>3.Low switching losses<br>4.Short turn-off time | Self-commutated inverters     Ac motor speed control | inverters                     | inverters   |                         | ZK:Fast Recovery Diodes DS:Reversely Switching Dynistors |           |  |
| Turn-off time            | 18–150 μ S | 5.Hermetic metal cases with ceramic insulators                                   | 5.General power switching applications               |                               | KM:Pulse Power Thyristors   |                         |  |           |  |

| High Frequency Thyristors |           |  |  |  |  |
|---------------------------|-----------|--|--|--|--|
| Key<br>Parameters         | Range     | Features   | Typical Applications                                 |  |  |
| Current                   | 480-1730A | gates  | 1.Inductive heating<br>2.Electronic welders          |  |  |
| Voltage                   |           | 2.Fast turn-on and high di/dt<br>3.Low switching losses<br>4.Short turn-off time | 3.Self-commutated inverters 4.Ac motor speed control |  |  |
| Γum–off time              | 5-36 µ S  | 5.Hermetic metal cases with ceramic insulators                                   | 5.General power switching applications               |  |  |

| BI-directional Control Thyristors |           |   |  |  |  |
|-----------------------------------|-----------|---|--|--|--|
| Key<br>Parameters                 | Range     | Features  | Typical Applications                           |  |  |
| Current                           | 520-930A  |   | 1.High power industrial and power transmission |  |  |
| Voltage                           | 500-1800V | 2.Hermetic metal cases with<br>ceramic insulators |  |  |  |
| Surge current                     | 5-8.8KA   | 3.Capsule packages for double sided cooling       | 4.Soft starters for induction motors           |  |  |

# Non Symmetric Fast Turn-Off Thyristors Outline Key Parameters blocking voltage backward voltage 200–1000V 1.Fast turn-on and high di/dt voltage Surge current 30KA Outline Applications Applicable to series resonant inverter power supply

|                   | Rectifier Dioes |   |  |  |  |  |
|-------------------|-----------------|---|--|--|--|--|
| Key<br>Parameters | Range           | Features  | Typical Applications   |  |  |  |
| Current           | 500-8000A       | 1.Low forward voltage drop                              | 1.All purpose high power rectifier diodes                            |  |  |  |
| Voltage           | 200-6500V       | 2.Reverse voltage up to 6500 v<br>3.Capsule type metal- | 2.High power resistance welding equipment     3.Non-controllable and |  |  |  |
| Surge current     | 5-80KA          | ceramic packages for doubl sided coolin                 | half-controllable rectifiers<br>4.Snubber diodes                     |  |  |  |

| Fast Recovery Diodes |           |  |   |  |  |
|----------------------|-----------|--|---|--|--|
| Key<br>Parameters    | Range     | Features   | Typical Applications                                  |  |  |
| Current              | 430-4580V |  | 1.Inverse diodes for power transistors,GTO thyristors |  |  |
| Voltage              | 200-5000V | 3.Up to 5000 v reverse voltage<br>4.Capsule type metal-ceramic | 2.AC motor control 3.Snubber diodes and free-         |  |  |
| Surge current        |           | packages for double sided                                      | wheeling diodes<br>4.UPS                              |  |  |

## Pulse Power Device

| Features<br>1.Interdigitate<br>2.Fast turn-o<br>3.Low switch | n and high d   |        |         |       |         | Application |        | ly       |                     |
|--|----------------|--------|---------|-------|---------|-------------|--------|----------|---------------------|
|  | IPK            | VDDM   | V/DDM 4 | di/dt | ability | dv/dt       | Tim N  | Mounting | 0.45                |
| Type   | tp0.3~2ms VDRM | VDRIVI | VHHIVI  | di/dt | IPK     | uv/ut       | ijiti  | Force    | Outline             |
|  | kA             | kV     | kV      | Αμs   | kA      | Wμs         | °C     | kN       |                     |
| Voltage to 45  | 000V           |        |         |       |         |             |        |          |                     |
| T100KPJ  | 140            | 4000   | 4000    | 1500  | 140     | 1000        | 90     | 90~113   |                     |
| H100KMM  | 150            | 4200   | 4200    | 2000  | 150     | 1000        | 100    | 90~113   | 2000                |
| H125KMM  | 200            | 4500   | 4500    | 2000  | 200     | 1000        | 100    | 90~120   | TECHSEN VSSKKEOTORO |
| Voltage to 52  | V000           |        |         |       |         |             |        |          |                     |
| H125KMN  | 150            | 5000   | 5000    | 1500  | 150     | 1000        | 100    | 90~120   |                     |
|  |                |        |         |       | Pu      | Ise Pov     | ver As | sembly   |                     |

### Features

Pulse power semiconductor devices and assembly, 10-300KA, 10-40KV, have advantages with large surge current, fast turn-on, high di/dt, etc. As per different application at customers, special pulse thyristor, super fast semiconductor devices can be designed in assembly structures which could provide whole electrical functions including trigger, protection etc. Special pulse assembly solution can be provided according to customers application conditions and requirements. Application: environment protection facility, laser facility, electromagnetic drive, etc.





Outline



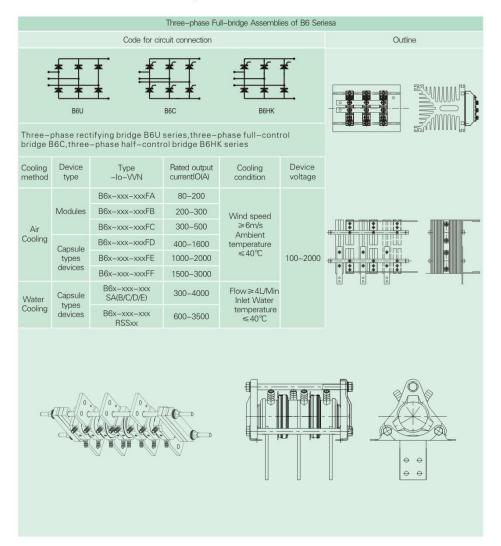
# Power Modules

|                   |             | Thyristor Modules   | Outline   |                        |
|-------------------|-------------|---|---|------------------------|
| Key<br>Parameters | Range       | Features  | Typical Applications  |                        |
| Current           | 26-1200A    | 2. International standard package   | 2.Various rectifiers     3.Contactless switches                                   | W W                    |
| Voltage           | 600-3600V   | 4.Air–cooling or water–cooling  | 4.Soft start AC motor<br>control<br>5.Welding power supply<br>6.DC supply for PWM |                        |
| Surge current     | 0.65-34KA   | 5.Simple mounting and easy<br>maintenance<br>6.Space and weight saving                                | inverter 7.Battery DC chargers or discharge                                       |                        |
|                   |             | Diode Modules   |   |                        |
| Key<br>Parameters | Range       | Features  | Typical Applications  |                        |
| Current           | 26-1200A    | 2. International standard package   | 1.AC/DC Motor drives<br>2.Various rectifiers                                      |                        |
| Voltage           | 600-3600V   | Pressure contact technology with increased power cycling capability     Air-cooling or water-cooling  | 3.Soft start AC motor<br>control<br>4.(TSC)SVC<br>5.Welding power supply          | Manual, Sylve-9 - Hand |
| Surge current     | 0.65-34KA   | 5.Simple mounting and easy<br>maintenance<br>6.Space and weight saving                                | 6.DC supply for PWM inverter  |                        |
|                   | Fast Turn-c | off Thyristor/Fast Recovery Diode   | e Modules   |                        |
| Key<br>Parameters | Range       | Features  | Typical Applications  |                        |
| Current           | 75-400A     | 1.Isolated mounting base, 2500V~<br>2.International standard package<br>3.Pressure contact technology | 4 leventee  | Ble lan                |
| Voltage           | 600-1600V   | with increased power cycling capability 4.Simple mounting and easy                                    | rith increased power cycling 2.Inductive heating apability                        | Black Black            |
| Turn-off time     | 15–35 μ S   | maintenance<br>5.Space and weight saving  |   |                        |
|                   |             | Fast Recovery Diode Modules   |   |                        |
| Key<br>Parameters | Range       | Features  | Typical Applications  |                        |
| Current           | 75–400A     | 1.Isolated mounting base, 2500V~<br>2.International standard package<br>3.Pressure contact technology | 1.Inverter 2.Inductive heating 3.Chopper  | ***                    |
| Voltage           | 600-1600V   | with increased power cycling capability 4.Simple mounting and easy                                    |   | Mary Mary State of     |
| Recovery time     | 1.5-4 µ S   | maintenance<br>5.Space and weight saving  |   |                        |

|                   | Single      | /Three phases rectification bridge   | modules   | Outline     |
|-------------------|-------------|--|---|-------------|
| Kev               | T can       | _  |   | Oduirle     |
| Parameters        | Range       | Features   | Typical Applications  |             |
| Current           | 50-200A     | 1.Isolated mounting base, 2500V~<br>2.International standard package   | nternational standard package 2.DC supply for PVVM                |             |
| Voltage           | 600-1800V   | Soider joint technology with a creased power cycling capability space and weight saving support of the control of the creation |   |             |
| Surge current     | 5.8-7.8KA   | 150° C<br>6.Low forward voltage drop   | 6.Electric drives and auxiliaries 7.Inverter welder               |             |
|                   |             | Diode Modules(Non-isolated type  | )   |             |
| Key<br>Parameters | Range       | Features   | Typical Applications  |             |
| Current           | 50-300A     | 1.Non-isolated. Mounting base as common anode or cathode terminal  | 1.Welding Power Supply  | El a la     |
| Voltage           | 800-1800V   | 2.International standard package<br>3.Pressure contact technology with<br>increased power cycling capability   | 2.Various DC power<br>supplies     3.DC supply for PWIVI inverter | 100000      |
| Surge current     | 1.4-10KA    | 4.High surge current<br>5.Low forward voltage drop   | livertei  |             |
|                   | Three ph    | nases rectification bridge+ Thyristo   | r modules   |             |
| Key<br>Parameters | Range       | Features   | Typical Applications  |             |
| Current           | 50-200A     | 1.Isolated mounting base, 2500V~<br>2.International standard package<br>3.Solder joint technology with   | 1. Supplies for DC power  |             |
| Voltage           | 600-1800V   | increased power cycling capability 4. Simplicity of design, module and   | equipment<br>2.Field supply for DC<br>motors                      |             |
| Surge current     | 0.73-1.85KA | SCR rectifier bridge, small volume, light weigh  | 3.Inverter welder   |             |
|                   | Thyri       | istor(/Diode ) Modules(Non-isolate   | d type)   |             |
| Key<br>Parameters | Range       | Features   | Typical Applications  |             |
| Current           | 50-300A     | Non-isolated. Mounting base as common anode or cathode terminal  | Nelding Power Supply     Various DC power                         | (m) (p) (p) |
| Voltage           | 800-1800V   | 2.International standard package<br>3.Pressure contact technology with<br>increased power cycling capability   | supplies 3.DC supply for PWM inverter 4.Field supply for DC       |             |
| Surge current     | 1.2-8.3KA   | High surge current     Low forward voltage drop  | 4.Field supply for DC motors                                      |             |

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# Heatsink / Assembly



| Cooling method        | Туре   | Shape | Туре  | Shape      |
|-----------------------|--------|-------|-------|------------|
|                       | SS11   |       |       |            |
|                       | SS12   |       | RSS51 |            |
|                       | SS13   |       |       |            |
|                       | SS14   |       |       |            |
|                       | SS15   |       |       |            |
|                       | SS16   |       |       |            |
|                       | SS17   |       |       |            |
|                       | SS11BL |       |       |            |
|                       | SS12BL |       |       |            |
|                       | SS13BL | A.C.  |       | pm ( . /p/ |
|                       | SS14BL |       | RSS61 |            |
|                       | SS15BL |       |       |            |
|                       | SS16BL |       |       |            |
| Water<br>Cooling      | SS17BL |       |       |            |
| Cooling               | RSS11  |       | DSS3  |            |
|                       | RSS21  |       | DSS5  |            |
|                       | RSS41  |       | DSS8  |            |
|                       | RSS31  |       | HSS3  |            |
|                       | SF12   |       |       |            |
| Forced<br>air cooling | SF13   |       |       |            |
|                       | SF14   |       |       |            |
|                       | SF15   |       | Wxx   |            |
|                       | 00     |       |       |            |
|                       | SF16   |       |       |            |



# Application



# Quality Control & Certificate



## Product Line Overview



















